

ISC Silicon PNP Power Transistors

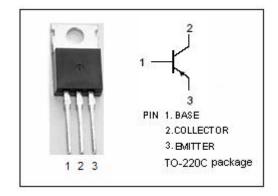
TIP42F

DESCRIPTION

- DC Current Gain -hFE = 30(Min)@ IC= -0.3A
- · Collector-Emitter Sustaining Voltage-
 - : V_{CEO(SUS)} = -160V(Min)
- Complement to Type TIP41F
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

Designed for use in general purpose amplifer and switching applications

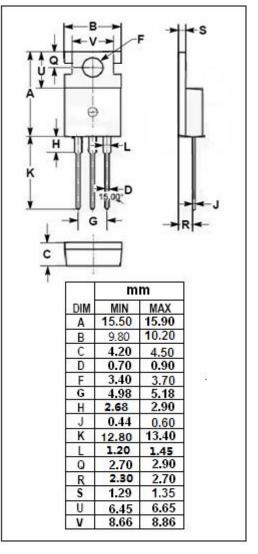


ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	-200	٧
V _{CEO}	Collector-Emitter Voltage	-160	V
V _{EBO}	Emitter-Base Voltage	-5	V
Ic	Collector Current-Continuous	-6	А
I _{CM}	Collector Current-Peak	-10	Α
I _B	Base Current	-3	Α
Pc	Collector Power Dissipation T_C =25 $^{\circ}$ C	65	
	Collector Power Dissipation T _a =25℃	2	W
T _j	Junction Temperature 150		$^{\circ}$
T _{stg}	Storage Temperature Range	-65~150	$^{\circ}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT
R _{th j-c}	Thermal Resistance,Junction to Case	1.92	°C/W
R _{th j-a}	Thermal Resistance, Junction to Ambient	62.5	°C/W





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ELECTRICAL CHARACTERISTICS

T_C=25°C unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT	
$V_{\text{CEO(SUS)}}$	Collector-Emitter Sustaining Voltage	I _C = -30mA; I _B = 0	-160		V	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -6A; I _B = -1.5A		-1.5	V	
V _{BE(on)}	Base-Emitter On Voltage	Ic= -6A; VcE= -4V		-2.0	V	
I _{CBO}	Collector Cutoff Current	V _{CB} = -200V; I _E = 0		-0.4	mA	
I _{CEO}	Collector Cutoff Current	V _{CE} = -90V; I _B = 0		-0.7	mA	
ІЕВО	Emitter Cutoff Current	V _{EB} = -5V; I _C = 0		-1.0	mA	
h _{FE-1}	DC Current Gain	I _C = -0.3A; V _{CE} = -4V	30			
h _{FE-2}	DC Current Gain	I _C = -3A ; V _{CE} = -4V	15			
fτ	Current-Gain—Bandwidth Product	I _C = -0.5A; V _{CE} = -10V	3		MHz	
Switching Time						
t _{on}	Turn-On Time	I_{C} = -6A; I_{B1} = - I_{B2} = -0.6A; $V_{BE(off)}$ = -4V, R_{L} = 5 Ω		0.6	μS	
t _{off}	Turn-Off Time			1.0	μ S	

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